

Docket No.: T2171.0196/P196

(PATENT)

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of:

Harumitsu Fujita

Application No.: 09/873,580

Group Art Unit: 2823

Filed: June 4, 2001

Examiner: F. Toledo

For: MULTI-VOLTAGE LEVEL

SEMICONDUCTOR DEVICE AND ITS

MANUFACTURE

AMENDMENT/SUBMISSION

U.S. Patent and Trademark Office 220 20th Street S. Customer Window, Mail Stop Amendment Crystal Plaza Two, Lobby, Room 1B03 Arlington, VA 22202

Dear Sir:

In response to the Office Action mailed June 28, 2004, please amend the aboveidentified application as follows: Application No.: 09/873,580 Docket No.: T2171.0196/P196

FEE CALCULATION

Any additional fee required has been calculated as follows:

___ If checked, "Small Entity" status is claimed.

	Claims Remaining After Amendment	Highest Number Previously Paid	Number Extra Claims Present	Rate	Additional Fee
Total	13	- 20* =		X	
Independent	2	- 3** =		Х	
First presentation	of Multiple Depe	endent Claim(s)	(if applicable)		
				TOTAL	0.00

^{*}not less than 20

No additional fee is required.

In the event a fee is required or if any additional fee during the prosecution of this application is not paid, the Patent Office is authorized to charge the underpayment to Deposit Account No. 50-2215.

CONTINGENT EXTENSION REQUEST

If this communication is filed after the shortened statutory time period had elapsed and no separate Petition is enclosed, the Commissioner of Patents and Trademarks is petitioned, under 37 CFR 1.136(a), to extend the time for filing a response to the outstanding Office Action by the number of months which will avoid abandonment under 37 CFR 1.135. The fee under 37 CFR 1.17 should be charged to our Deposit Account No. 50-2215.

^{**} not less than 3